



**DMP2900UW** 

#### **Product Summary**

BV <sub>DSS</sub>	Rds(on)	ID TA = +25°C
	750mΩ @ V <sub>GS</sub> = -4.5V	-0.6A
-20V	1050mΩ @ V <sub>GS</sub> = -2.5V	-0.5A
	1500mΩ @ V <sub>GS</sub> = -1.8V	-0.45A

#### **Description and Applications**

This new generation MOSFET is designed to minimize the on-state resistance ( $R_{DS(ON)}$ ) yet maintain superior switching performance, which makes it ideal for high-efficiency power management applications.

- DC-DC Converters
- Load Switch
- Power Management Functions

## Features and Benefits

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

P-CHANNEL ENHANCEMENT MODE MOSFET

#### **Mechanical Data**

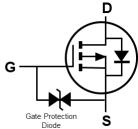
- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed Over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 3
- Weight: 0.006 grams (Approximate)



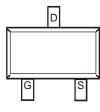


**SOT323** 

Top View



Equivalent Circuit



Top View

#### Ordering Information (Note 4)

Part Number	Case	Packaging
DMP2900UW-7	SOT323	3,000/Tape & Reel
DMP2900UW-13	SOT323	10,000/Tape & Reel

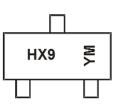
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

#### **Marking Information**



HX9 = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: I = 2021) M = Month (ex: 9 = September)

Date Code Key

Year	2018		2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	F			J	К	L	М	Ν	0	Р	R	S
Manth		Feb	Mar	Apr	May	Jun	Jul	Διια	Sep	Oct	Nov	Dec
Month	Jan	гер	IVIdi	Арі	way	Juli	Jui	Aug	Seh	001	NOV	Dec



## Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	Vdss	-20	V		
Gate-Source Voltage	V <sub>GSS</sub>	±6	V		
Continuous Drain Current (Note 6) $V_{GS}$ = -4.5V	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	-0.6 -0.5	А
Maximum Body Diode Forward Current (Note 6)	ls	-0.45	A		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%	IDM	-2.5	A		

#### **Thermal Characteristics**

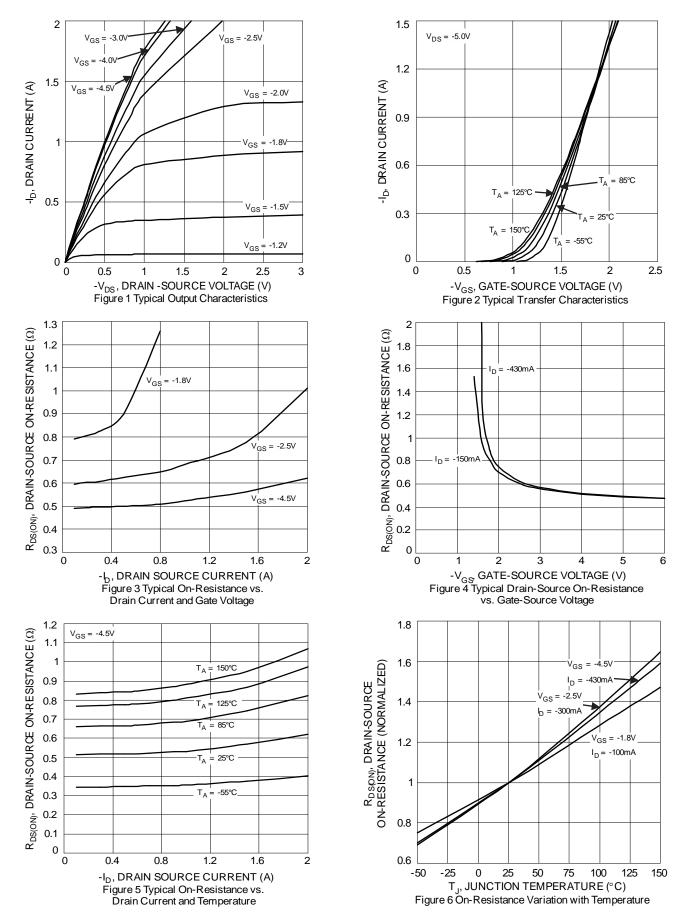
Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	0.3	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	393	°C/W
Total Power Dissipation (Note 6)		PD	0.5	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Rəja	272	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C	

#### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

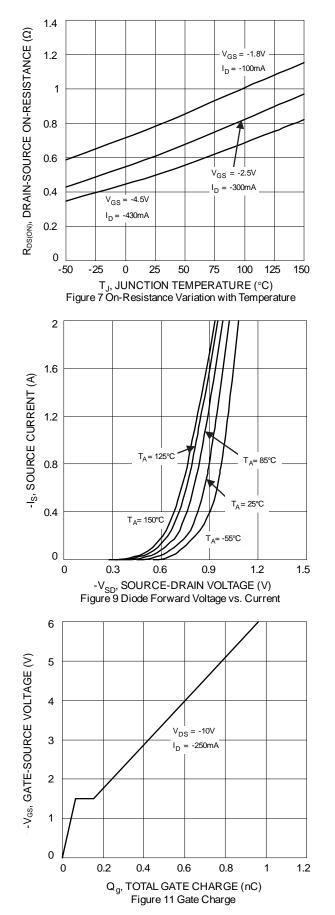
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						·
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-20	—	_	V	$V_{GS} = 0V, I_D = -250 \mu A$
Zero Gate Voltage Drain Current TJ = +25°C	IDSS	_	—	-100	nA	V <sub>DS</sub> = -20V, V <sub>GS</sub> = 0V
Gate-Source Leakage	IGSS	_	—	±2.0	μA	$V_{GS} = \pm 4.5 V, V_{DS} = 0 V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	Vgs(th)	-0.5	_	-1.0	V	$V_{DS} = V_{GS}$ , $I_D = -250 \mu A$
			_	0.75 1.05 1.5		$V_{GS} = -4.5V, I_{D} = -430mA$
Static Drain-Source On-Resistance	RDS(ON)		_		Ω	$V_{GS} = -2.5V, I_{D} = -300 \text{mA}$
			—			$V_{GS} = -1.8V, I_D = -150mA$
Diode Forward Voltage	V <sub>SD</sub>	_	—	-1.2	V	$V_{GS} = 0V, I_{S} = -150mA$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	_	49	_	pF	
Output Capacitance	Coss	_	12	—	pF	V <sub>DS</sub> = -16V, V <sub>GS</sub> = 0V, - f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	3.4	_	pF	1 = 1:00012
Total Gate Charge	Qg	_	0.7	_	nC	
Gate-Source Charge	Qgs	_	0.1	_	nC	VGS = -4.5V, VDS = -10V, D = -250mA
Gate-Drain Charge	Q <sub>gd</sub>		0.1		nC	ID = -25011A
Turn-On Delay Time	td(on)	_	16	_	ns	
Turn-On Rise Time	tR	_	15		ns	$V_{DD} = -10V, V_{GS} = -4.5V,$
Turn-Off Delay Time	tD(OFF)	—	213	—	ns	$R_{L} = 47\Omega, R_{G} = 10\Omega,$ $D_{D} = -200 mA$
Turn-Off Fall Time	tF		89		ns	
Reverse Recovery Time	t <sub>RR</sub>	_	10.5		ns	I <sub>F</sub> = -1.0A, di/dt = 100A/µs
Reverse Recovery Charge	Q <sub>RR</sub>	_	1.8	_	nC	$IF = -1.0A$ , $dI/dl = 100A/\mu S$

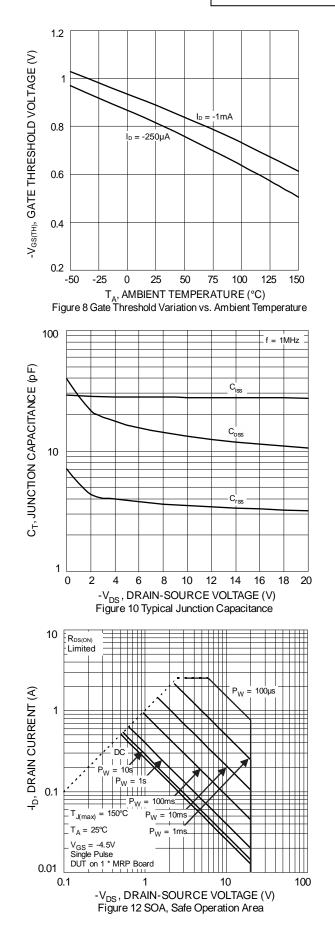
 Device mounted on FR-4 substrate PCB, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PCB, 2oz copper, with 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing. Notes:





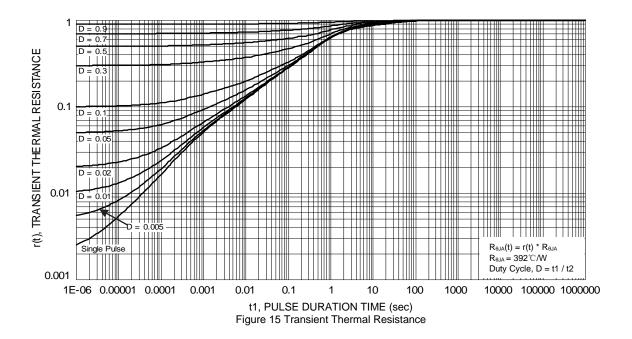






DMP2900UW Document number: DS41296 Rev. 5 - 2

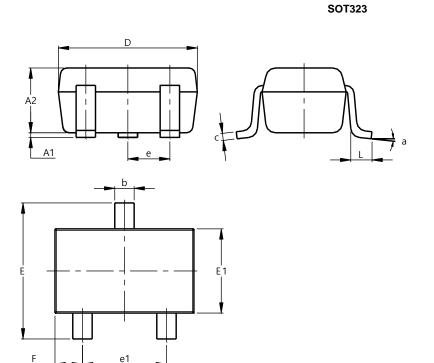






#### **Package Outline Dimensions**

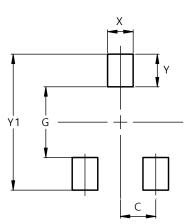
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SOT323								
Dim	Min	Max	Тур						
A1	0.00	0.10	0.05						
A2	0.90	1.00	0.95						
b	0.25	0.40	0.30						
С	0.10	0.18	0.11						
D	1.80	2.20	2.15						
Е	2.00	2.20	2.10						
E1	1.15	1.35	1.30						
е	C	).650 B	SC						
e1	1.20	1.40	1.30						
F	0.375	0.475	0.425						
L	0.25	0.40	0.30						
а	0°	8°							
All	Dimen	sions i	in mm						

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



## SOT323

Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.470
Y	0.600
Y1	2.500



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